

# ERC35-02

High Efficiency Rectifier

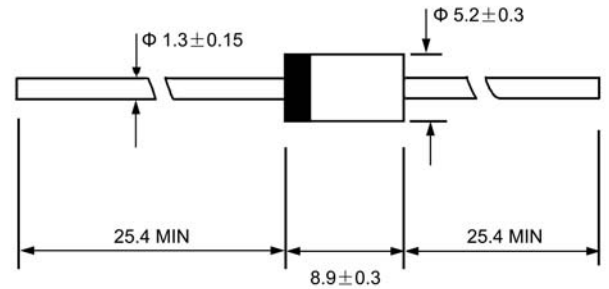
**VOLTAGE RANGE: 200 V**

**CURRENT: 2.5 A**

**DO - 27**

## Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0



Dimensions in millimeters

## Mechanical Data

- ◇ Case: JEDEC DO--27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

|   |                 | ERC35 - 02      | UNITS              |
|---|-----------------|-----------------|--------------------|
| Maximum recurrent peak reverse voltage  | $V_{RRM}$       | 200             | V                  |
| Maximum RMS voltage   | $V_{RMS}$       | 140             | V                  |
| Maximum DC blocking voltage   | $V_{DC}$        | 200             | V                  |
| Maximum average forward rectified current<br>9.5mm lead length, @ $T_A=75^\circ\text{C}$                          | $I_{F(AV)}$     | 2.5             | A                  |
| Peak forward surge current<br>8.3ms single half-sine-wave<br>superimposed on rated load @ $T_J=125^\circ\text{C}$ | $I_{FSM}$       | 50.0            | A                  |
| Maximum instantaneous forward voltage<br>@ 2.5A   | $V_F$           | 1.2             | V                  |
| Maximum reverse current @ $T_A=25^\circ\text{C}$<br>at rated DC blocking voltage @ $T_A=100^\circ\text{C}$        | $I_R$           | 5.0<br>100.0    | $\mu\text{A}$      |
| Maximum reverse recovery time (Note1)   | $t_{rr}$        | 100             | ns                 |
| Typical junction capacitance (Note2)  | $C_J$           | 70              | pF                 |
| Typical thermal resistance (Note3)  | $R_{\theta JA}$ | 30              | $^\circ\text{C/W}$ |
| Operating junction temperature range  | $T_J$           | - 55 ---- + 150 | $^\circ\text{C}$   |
| Storage temperature range   | $T_{STG}$       | - 55 ---- + 150 | $^\circ\text{C}$   |

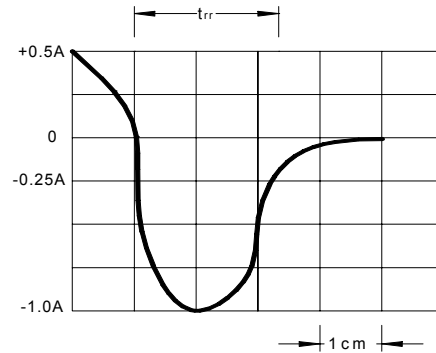
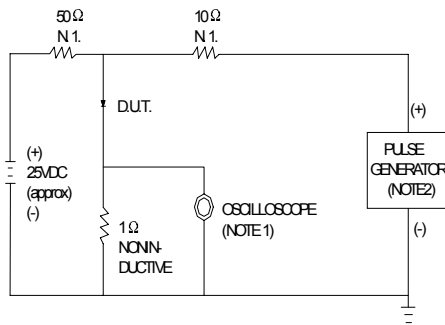
NOTE: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $t_{rr}=0.25\text{A}$ .

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

## Ratings AND Characteristic Curves

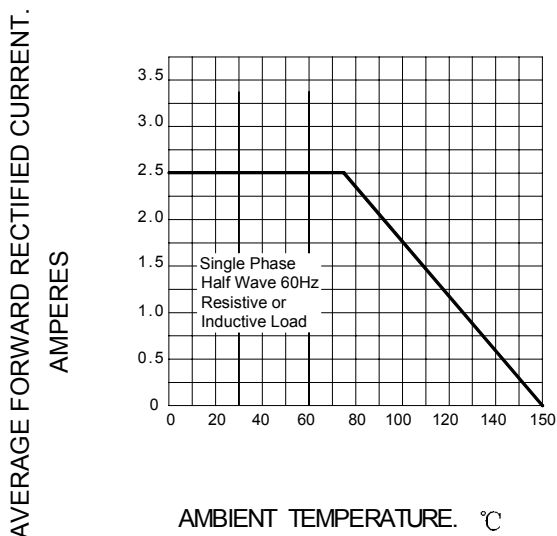
**FIG.1 –TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



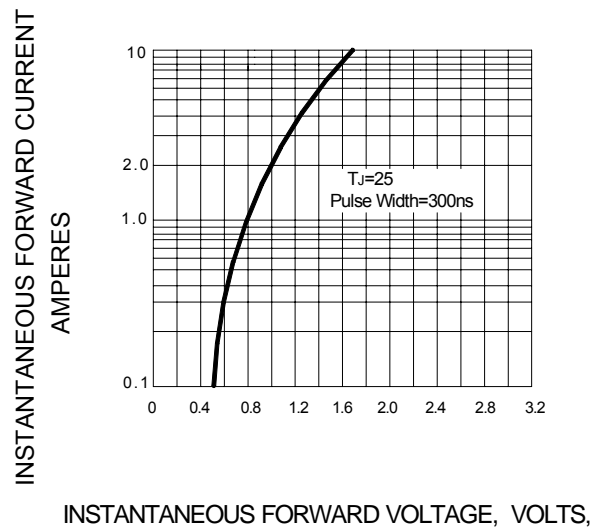
NOTES: 1. RISE TIME=7ns MAX.INPUT IMPEDANCE=1MΩ.22pF  
2. RISE TIME=10ns MAX.SOURCE IMPEDANCE=50Ω.

SET TIME BASE FOR 20/30 ns/cm

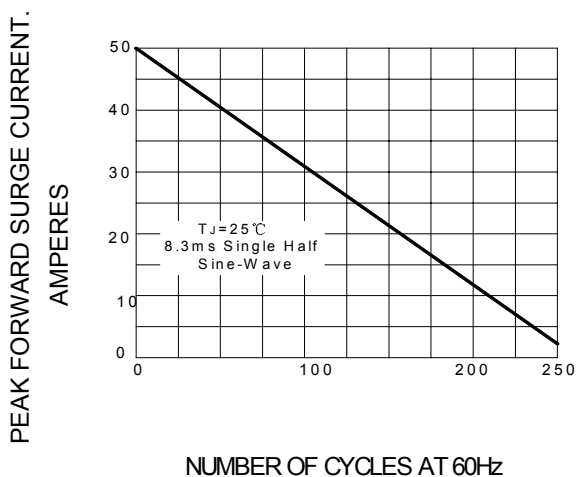
**FIG.3 –FORWARD DERATING CURVE**



**FIG.4–TYPICAL FORWARD CHARACTERISTIC**



**FIG.5–PEAK FORWARD SURGE CURRENT**



**FIG.6–TYPICAL JUNCTION CAPACITANCE**

